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View Online at https://aerobasegroup.com/nsn/5961-00-164-2032 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.380 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 51.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 900.00 milliamperes dc current in reverse breakdown region and 245.00 milliamperes voltage regulator diode current **Power Rating Per Characteristic:** 50.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Design analysis **Nuclear Hardness Critical Feature:** Hardened **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 pin **Specification Data:**

N/a
Unit Of Measure:

Shelf Life:

81349-mil-s-19500/114 government specification

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Demilitarization:

No

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